

PSR Flyback DC/DC Converter Transformer Design for mHEV Applications

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Magnetic component design is an important aspect when implementing isolated DC/DC converters. For the primary-side regulated (PSR) flyback converter in particular, the transformer plays a critical role as it sets the flyback operating mode boundaries and has an outsized impact on the performance of the converter.

This tech note describes a condensed transformer design procedure for a low-power PSR flyback DC/DC converter in an automotive application. The steps are useful whether the transformer design is carried out in-house or outsourced to a magnetic component vendor.

mHEV Power Solution

As an example, consider a [mild-hybrid electric vehicle \(mHEV\)](#) system with 12 V and 48 V batteries as shown in [Figure 1](#). The isolated DC/DC power supply highlighted in red provides a tightly-regulated 12-V bias rail on the 48-V side.

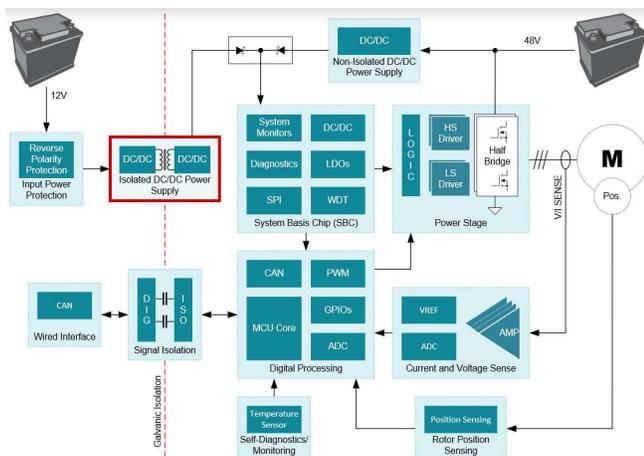
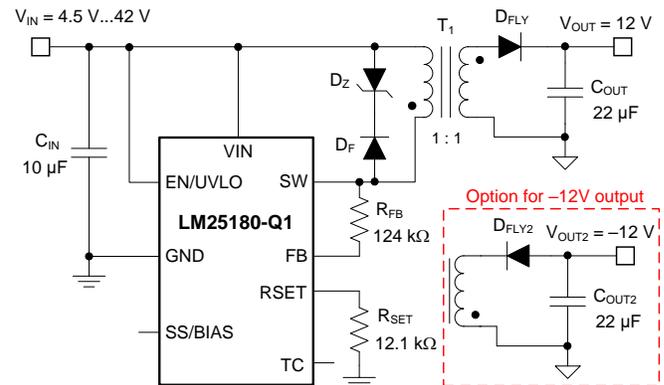


Figure 1. mHEV System Block Diagram

Figure 2 shows the LM25180-Q1 PSR flyback DC/DC converter schematic with a 12-V output up to 200 mA. Additional outputs are easily configured depending on the application requirements. The schematic above includes an optional negative output if bipolar output rails (± 12 V) are required.

Note that the LM25180-Q1 does not need an optocoupler, voltage reference or transformer auxiliary winding for output voltage regulation.

Instead, the device senses the reflected isolated output voltage from the primary-side flyback voltage waveform, resulting in accurate load and line regulation performance. This simplifies the design, enables a smaller solution size and requires only one component crossing the isolation barrier.



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Figure 2. PSR Flyback DC/DC Converter Schematic

Designing a Flyback Magnetic Component

The following outlines a 6-step transformer design procedure tailored for a PSR flyback DC/DC converter.

1. Define Specification

Table 1 gives the relevant design parameters for this mHEV application example.

Table 1. PSR Flyback Specifications

SYMBOL	PARAMETER	VALUE
V_{IN}	Min, nom, max input voltage	5.5 V, 13.5 V, 42 V
V_{OUT}, I_{OUT}	Output voltage and current	12 V, 0.2 A
F_{SW}	Full-load switching frequency at min/nom/max V_{IN}	100 kHz (BCM), 220 kHz (BCM), 350 kHz (DCM)
I_{PRI-PK}	Peak primary current	1.2 A
V_D	Flyback diode voltage drop	0.4 V

Equation 1 gives the duty cycle of a flyback converter when operating in boundary conduction mode (BCM).

$$D = \frac{(V_{OUT} + V_D) \cdot N_{PS}}{V_{IN} + (V_{OUT} + V_D) \cdot N_{PS}} \quad (1)$$

Assuming a maximum duty cycle of 70% at minimum input voltage, find an initial estimate for the transformer turns ratio using Equation 2.

$$N_{PS} = \frac{D_{MAX}}{1-D_{MAX}} \cdot \frac{V_{IN(min)}}{V_{OUT} + V_D} = \frac{0.7}{1-0.7} \cdot \frac{5.5V}{12V + 0.4V} \approx 1 \quad (2)$$

2. Core Selection

Select a core based on the required output power. Refer to section 4 of the [Magnetics Design Handbook](#) for more detail. Choose an EP7 ferrite core for this application with relevant parameters given in Table 2.

Table 2. EP7 Ferrite Core Parameters

SYMBOL	PARAMETER	VALUE
A_e	Effective area (mm ²)	10.7
A_{min}	Minimum area (mm ²)	8.65
V_e	Effective volume (mm ³)	165
l_e	Effective length (mm)	15.5

3. Calculate Inductance

To ensure adequate time to reset the magnetizing current to zero, Equation 3 determines the minimum magnetizing inductance using current and off-time parameters specific to the LM25180-Q1.

$$L_{MAG} \geq \frac{V_{OUT} \cdot N_{PS} \cdot t_{OFF(min)}}{I_{PRI-PK(FFM)}} = \frac{12V \cdot 1 \cdot 0.45\mu s}{0.3A} = 18\mu H \quad (3)$$

A magnetizing inductance of 30 μH provides an acceptable design margin and enables the converter to operate in BCM at a lower switching frequency for a greater portion of the load and line range.

Using a core with 880- μm airgap that sets an inductance factor A_L of 25 nH per turn squared, calculate the number of primary turns using Equation 4. Given the unity turns ratio, the number of secondary turns is also 36.

$$N_p = \sqrt{\frac{L_{MAG}}{A_L}} = \sqrt{\frac{30\mu H}{25nH/Turns^2}} \approx 36 \quad (4)$$

4. Calculate Copper Loss

Determine the appropriate wire gauge and number of paralleled strands using the bobbin fit factor and buildup calculations found in the [Practical Magnetic Design: Inductor and Coupled Inductors Seminar](#).

As described there, derive the AC/DC wire resistance ratio due to skin effect at the applicable frequency. Selecting 34 AWG wire size for both primary and secondary, calculate the primary and secondary winding resistances as 180 m Ω based on the mean length of the bobbin per turn (MLT) of 17.9 mm.

Find the total copper loss using Equation 5 as 0.2 W.

$$P_{CU} = P_{CU-PRI} + P_{CU-SEC} = R_{PRI} \cdot I_{PRI-RMS}^2 + R_{SEC} \cdot I_{SEC-RMS}^2 = \frac{1}{3} \cdot \left[D \cdot R_{PRI} \cdot I_{PRI-PK}^2 + (1-D) \cdot R_{SEC} \cdot (N_{PS} \cdot I_{PRI-PK})^2 \right] \quad (5)$$

5. Calculate Flux Density and Core Loss

Given the minimum cross-sectional area of the selected core, calculate the peak flux density in an overcurrent (OC) condition using Equation 6 and ensure that it is less than the saturation level of the core material, typically 250 mT or higher for a ferrite. The flux cycles from zero to peak in the first quadrant of the B-H curve of the core.

$$B_{PK} = \frac{L_{MAG} \cdot I_{PRI-PK(OC)}}{N_p \cdot A_{min}} = \frac{30\mu H \cdot 2A}{36 \cdot 8.5mm^2} = 196mT \quad (6)$$

Find the flux density swing for core loss calculations using Equation 7.

$$B_{AC} = \frac{L_{MAG} \cdot I_{PRI-PK}}{2 \cdot N_p \cdot A_e} = \frac{30\mu H \cdot 1.2A}{2 \cdot 36 \cdot 10.7mm^2} = 47mT \quad (7)$$

Identify a specific power loss of 40 kW/m³ using flux density and frequency as parameters in the applicable characterization plot of the core vendor. Multiply by the effective volume to obtain a core loss of 7 mW.

5. Calculate Temperature Rise

Given a total power loss of 207 mW, use the core and bobbin effective thermal impedance of 40°C/W to estimate a temperature rise of 8°C.

Iterate these calculations as needed to obtain a transformer design optimized for the desired input voltage and ambient temperature ranges.

6. Construct Transformer

Figure 3 shows a transformer winding construction with single-filar primary and secondary windings. The split-primary winding sandwiches two secondary layers to obtain a low leakage inductance of 300 nH.

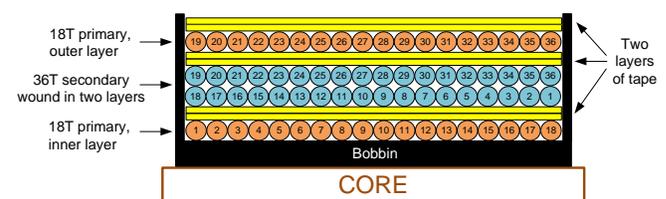


Figure 3. Interleaved Transformer Construction with Split-primary Winding

As functional grade isolation is typically sufficient for mHEV applications, two layers of tape are placed between adjacent primary and secondary layers.

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